# **Single Unbuffered Inverter**

The NL17SZU04 is a single unbuffered inverter in three tiny footprint package. The device performs much as LCX multi-gate products in speed and drive.

### **Features**

- Tiny SOT-353, SOT-553 and SOT-953 Packages
- Source/Sink ±16 mA at 4.5 V V<sub>CC</sub>
- Over-Voltage Tolerant Inputs and Outputs
- Pin For Pin with NC7SZU04P5X, TC7SZU04FU and TC7SZU04AFE
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

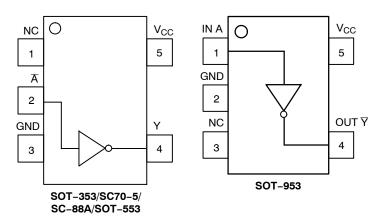


Figure 1. Pinout (Top View)



Figure 2. Logic Symbol



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SC-88A/SOT-353/SC-70-5 DF SUFFIX CASE 419A



**MARKING** 

**DIAGRAMS** 



SOT-553 XV5 SUFFIX CASE 463B



L6 = Specific Device Code

M = Date Code

■ = Pb-Free Package

(\*Note: Microdot may be in either location)



SOT-953 CASE 527AE



4 = Specific Device Code M = Month Code

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

## **PIN ASSIGNMENT**

(SOT-353/SC70-5/SC-88A/SOT-553)

Pin	Function
1	NC
2	A
3	GND
4	Y
5	V <sub>CC</sub>

## PIN ASSIGNMENT (SOT-953)

Pin	Function
1	IN A
2	GND
3	NC
4	OUT ₹
5	V <sub>CC</sub>

## **FUNCTION TABLE**

Input	Output Y = A
Α	Y
L	Н
Н	L

### **MAXIMUM RATINGS**

Symbol	Parameter	Value	Units
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage	-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage (SOT-353/SC70-5/SC-88A/SOT-553 Packages)	-0.5 to V <sub>CC</sub> + 0.5	V
V <sub>OUT</sub>	DC Output Voltage Output at High or Low State (SOT-953 Package) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to + 0.5	V
I <sub>IK</sub>	DC Input Diode Current	-50	mA
I <sub>OK</sub>	DC Output Diode Current V <sub>OUT</sub> < GND, V <sub>OUT</sub> > V <sub>CC</sub> (SOT–353/SC70–5/SC–88A/SOT–553 Packages)	±50	mA
I <sub>OK</sub>	DC Output Diode Current (SOT-953 Package) V <sub>OUT</sub> < GND	-50	mA
I <sub>OUT</sub>	DC Output Sink Current	±50	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T <sub>J</sub>	Junction Temperature Under Bias	+150	°C
$\theta_{\sf JA}$	Thermal Resistance SC-88A/SOT-353 (Note 1) SOT-553	350 496	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C SC–88A/SOT–353 SOT–553	186 135	mW
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	Class IC Class A N/A	V
I <sub>LATCHUP</sub>	Latchup Performance Above V <sub>CC</sub> and Below GND at 125°C (Note 5)	±100	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
   Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.
- 3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Units
V <sub>CC</sub>	DC Supply Voltage (Operating) Data Retention Only	1.65 1.5	5.5 5.5	V
V <sub>IN</sub>	DC Input Voltage	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage (SOT-353/SC70-5/SC-88A/SOT-553 Packages)	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage (SOT-953 Package)		V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0	100 20	ns/V

## DC ELECTRICAL CHARACTERISTICS

	Parameter	Condition	V <sub>CC</sub>	Т	_ <sub>A</sub> = 25°0		$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le 85^{\circ}\text{C}$		
Symbol			(V)	Min	Тур	Max	Min	Max	Units
V <sub>IH</sub>	High-Level Input		1.65 to 1.85	0.85 V <sub>CC</sub>			0.85 V <sub>CC</sub>		V
	Voltage		2.3 to 5.5	0.8 V <sub>CC</sub>			0.8 V <sub>CC</sub>		
$V_{IL}$	Low-Level Input		1.65 to 1.85			0.15 V <sub>CC</sub>		0.15 V <sub>CC</sub>	V
	Voltage		2.3 to 5.5			0.2 V <sub>CC</sub>		0.2 V <sub>CC</sub>	
Voн	High-Level Output Voltage V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>	$I_{OH} = -100 \mu A$ $I_{OH} = -3 mA$ $I_{OH} = -4 mA$ $I_{OH} = -6 mA$ $I_{OH} = -8 mA$ $I_{OH} = -12 mA$ $I_{OH} = -16 mA$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	V <sub>CC</sub> - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	V <sub>CC</sub> 1.52 2.1 2.4 2.7 2.5 4.0		V <sub>CC</sub> - 0.1 1.29 1.9 2.2 2.4 2.3 3.8		V
V <sub>OL</sub>	Low-Level Output Voltage V <sub>IN</sub> = V <sub>IH</sub> or V <sub>OH</sub>	$I_{OL} = 100 \ \mu\text{A}$ $I_{OL} = 3 \ \text{mA}$ $I_{OL} = 4 \ \text{mA}$ $I_{OL} = 6 \ \text{mA}$ $I_{OL} = 8 \ \text{mA}$ $I_{OL} = 12 \ \text{mA}$ $I_{OL} = 16 \ \text{mA}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5		0.08 0.20 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55		0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current (SOT-353/ SC70-5/SC-88A/ SOT-553 Packages)	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0			1		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = 5.5 V or GND	5.5			1		10	μΑ

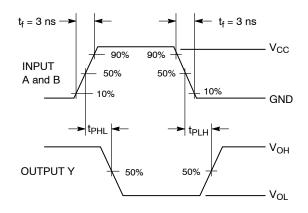
## AC ELECTRICAL CHARACTERISTICS $t_R$ = $t_F$ = 3.0 ns

			v <sub>cc</sub>	T <sub>A</sub> =	25°C	-40°C ≤ 1	Γ <sub>A</sub> ≤ 85°C	
Symbol	Parameter	Condition	(V)	Min	Max	Min	Max	Units
t <sub>PLH</sub>	Propagation Delay	$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	1.8 ± 0.15	1.0	11.7	1.0	12.1	ns
t <sub>PHL</sub>	(Figure 3 and 4)	$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	2.5 ± 0.2	0.8	6.2	0.8	6.5	
		$R_L = 1 M\Omega$ , $C_L = 15 pF$	$3.3 \pm 0.3$	0.5	4.5	0.5	4.8	
		$R_L = 500 \Omega, C_L = 50 pF$		1.0	6.0	1.0	6.5	
		$R_L = 1 M\Omega, C_L = 15 pF$	$5.0 \pm 0.5$	0.5	3.9	0.5	4.1	
		$R_L = 500 \Omega, C_L = 50 pF$		0.8	5.0	0.8	5.5	

### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	4.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	10 MHz, V <sub>CC</sub> = 3.3 V, V <sub>I</sub> = 0 V or V <sub>CC</sub> 10 MHz, V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	6.5 10	pF

<sup>6.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



INPUT

A 1-MHz square input wave is recommended for

Figure 3. Switching Waveform

Figure 4. Test Circuit

propagation delay tests.

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NL17SZU04DFT2G	SC-88A/SOT-353/SC-70-5 (Pb-Free)	3000 / Tape & Reel
NLV17SZU04DFT2G*	SC-88A/SOT-353/SC-70-5 (Pb-Free)	3000 / Tape & Reel
NL17SZU04XV5T2G	SOT-553 (Pb-Free)	4000 / Tape & Reel
NL17SZU04P5T5G	SOT-953 (Pb-Free)	8000 / Tape & Reel

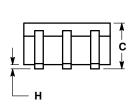
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

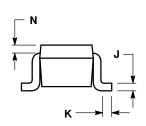
<sup>\*</sup>NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

## **PACKAGE DIMENSIONS**

## SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE L

G S **D** 5 PL 0.2 (0.008) M B M





- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

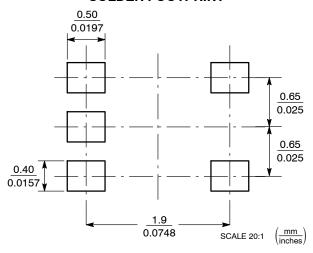
  2. CONTROLLING DIMENSION: INCH.

  3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.

  4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N	0.008 REF		0.20 REF		
S	0.079	0.087	2 00	2 20	

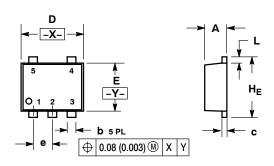
## **SOLDER FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## **PACKAGE DIMENSIONS**

## SOT-553 **XV5 SUFFIX** CASE 463B **ISSUE B**

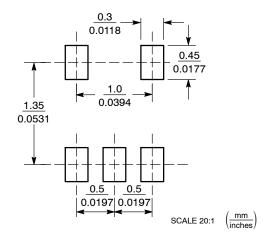


## STYLE 1: PIN 1. BASE 1 STYLE 2: PIN 1. CATHODE 2. EMITTER 1/2 3. BASE 2 4. COLLECTOR 2 5. COLLECTOR 1 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			TERS INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.13	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.063	0.067
E	1.10	1.20	1.30	0.043	0.047	0.051
е		0.50 BSC			0.020 BS0	
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1 60	1 70	0.059	0.063	0.067

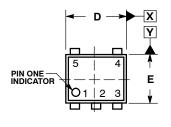
## **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

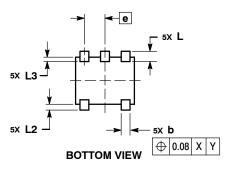
### PACKAGE DIMENSIONS

## SOT-953 CASE 527AE ISSUE E



**TOP VIEW** 

Α  $H_{\mathsf{E}}$ SIDE VIEW

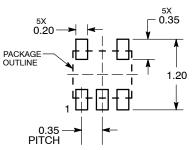


### NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE
- MINIMUM THICKNESS OF THE BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MIL	MILLIMETERS					
DIM	MIN	NOM	MAX				
Α	0.34	0.37	0.40				
b	0.10	0.15	0.20				
С	0.07	0.12	0.17				
D	0.95	1.00	1.05				
E	0.75	0.80	0.85				
е		0.35 BS	С				
HE	0.95	1.00	1.05				
L	0.175 REF						
L2	0.05	0.10	0.15				
L3			0.15				

### **SOLDERING FOOTPRINT\***



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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